

SANYO	No.3152	2SB1452/2SD2201
		PNP/NPN Epitaxial Planar Silicon Transistors 80V/7A Switching Applications

Features

- Surface mount type device making the following possible
 - Reduction in the number of manufacturing processes for 2SB1452/2SD2201-applied equipment
 - High density surface mount applications
 - Small size of 2SB1452/2SD2201-applied equipment
- Low collector-to-emitter saturation voltage
- Large current capacity

() : 2SB1452

Absolute Maximum Ratings at Ta = 25°C

			unit
Collector-to-Base Voltage	V _{CB0}	(-)90	V
Collector-to-Emitter Voltage	V _{CEO}	(-)80	V
Emitter-to-Base Voltage	V _{EBO}	(-)6	V
Collector Current	I _C	(-)7	A
Collector Current(Pulse)	I _{CP}	(-)12	A
Collector Dissipation	P _C	1.65	W
		40	W
Junction Temperature	T _j	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

T_c = 25°C

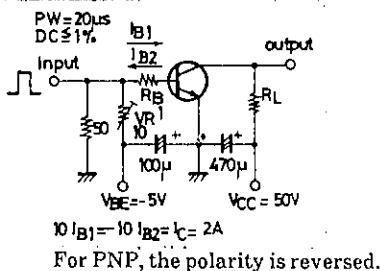
Electrical Characteristics at Ta = 25°C

			min	typ	max	unit
Collector Cutoff Current	I _{CB0}	V _{CB} = (-)80V, I _E = 0			(-)0.1	mA
Emitter Cutoff Current	I _{EBO}	V _{EB} = (-)4V, I _C = 0			(-)0.1	mA
DC Current Gain	h _{FE} (1)	V _{CE} = (-)2V, I _C = (-)1A	70*		280*	
	h _{FE} (2)	V _{CE} = (-)2V, I _C = (-)4A	30			
Gain-Bandwidth Product	f _T	V _{CE} = (-)5V, I _C = (-)1A		20		MHz
C-E Saturation Voltage	V _{CE(sat)}	I _C = (-)4A, I _B = (-)0.4A			0.4	V
					(-0.5)	
C-B Breakdown Voltage	V _{(BR)CBO}	I _C = (-)1mA, I _E = 0	(-)90			V
C-E Breakdown Voltage	V _{(BR)CEO}	I _C = (-)1mA, R _{BE} = ∞	(-)80			V
E-B Breakdown Voltage	V _{(BR)EBO}	I _E = (-)1mA, I _C = 0	(-)6			V
Turn-ON Time	t _{on}	See specified Test Circuit.		(0.2)0.1		μs
Storage Time	t _{stg}	"		(0.7)1.6		μs
Fall Time	t _f	"		(0.2)0.4		μs

* : The 2SB1452/2SD2201 are classified by 1A h_{FE} as follows:

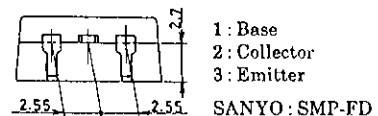
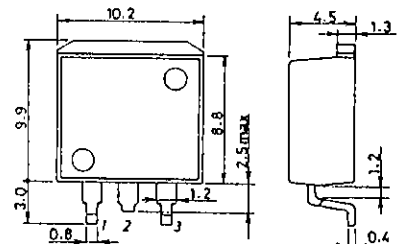
70 Q 140	100 R 200	140 S 280
----------	-----------	-----------

Switching Time Test Circuit

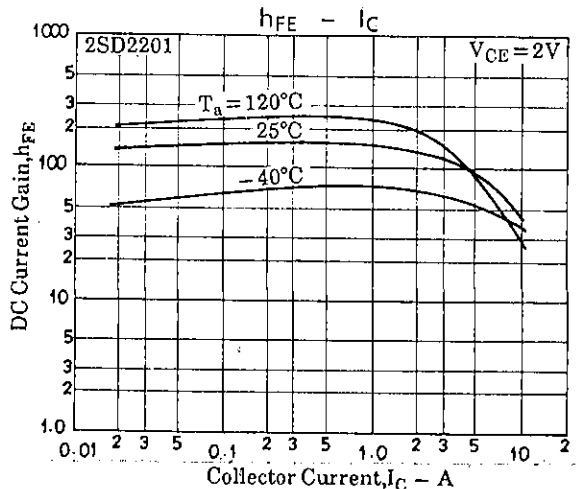
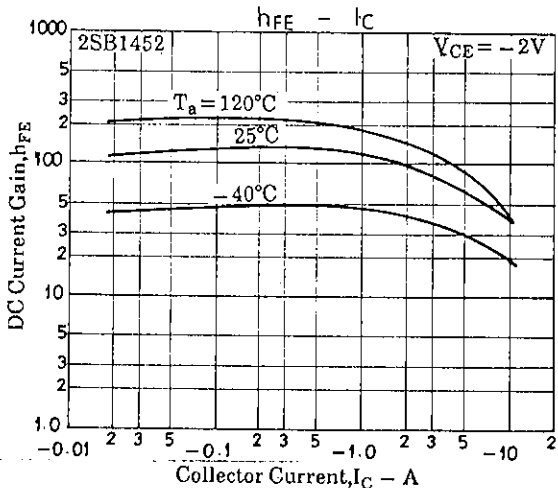
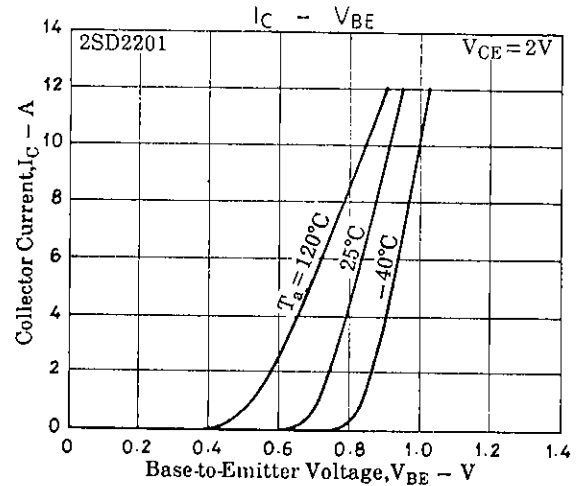
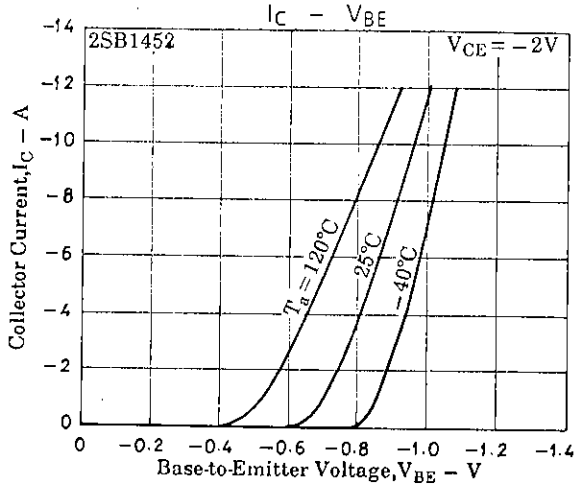
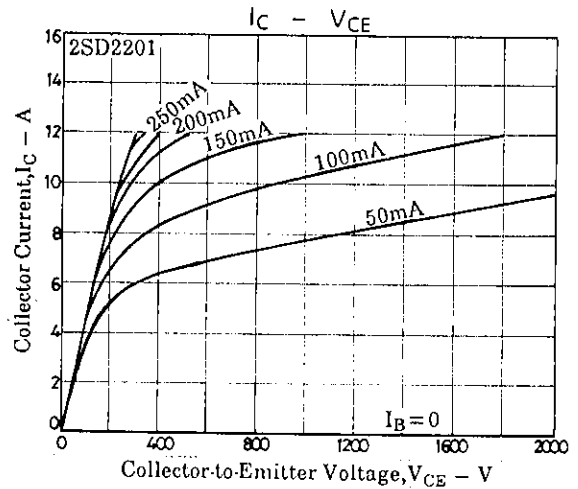
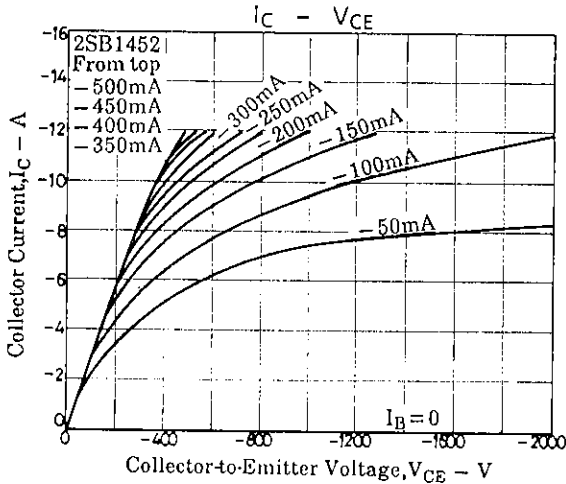
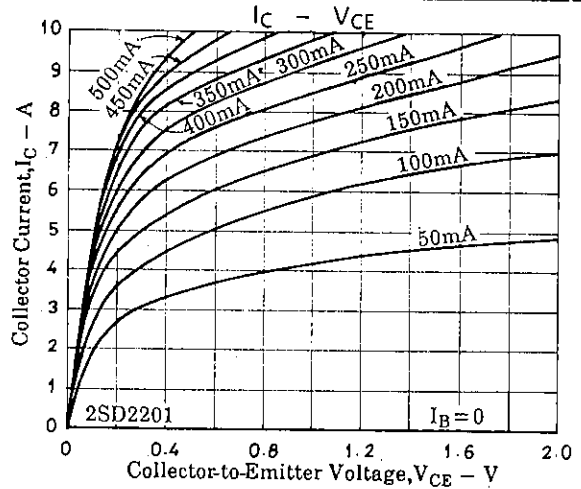
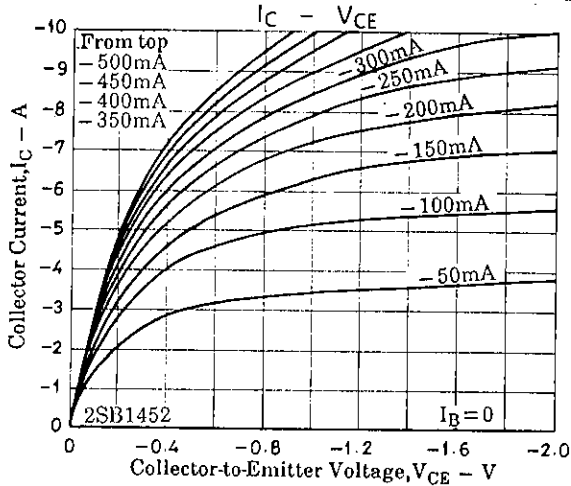


Unit (Resistance : Ω, Capacitance : F)

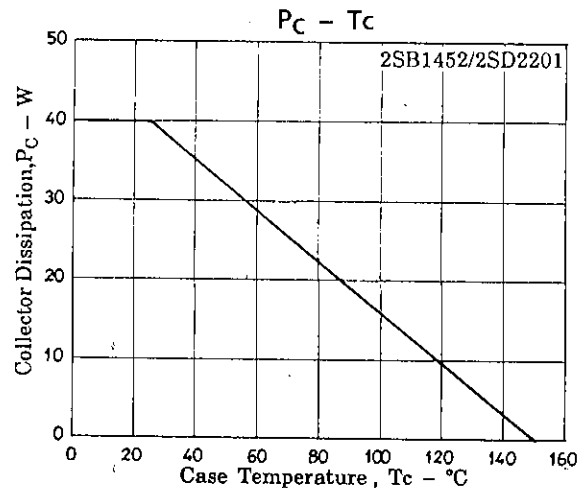
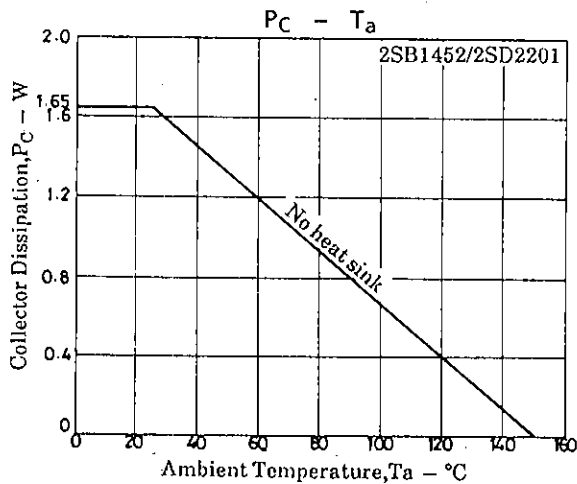
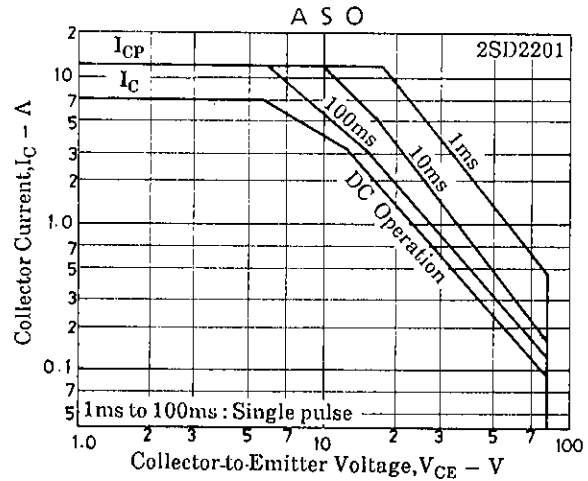
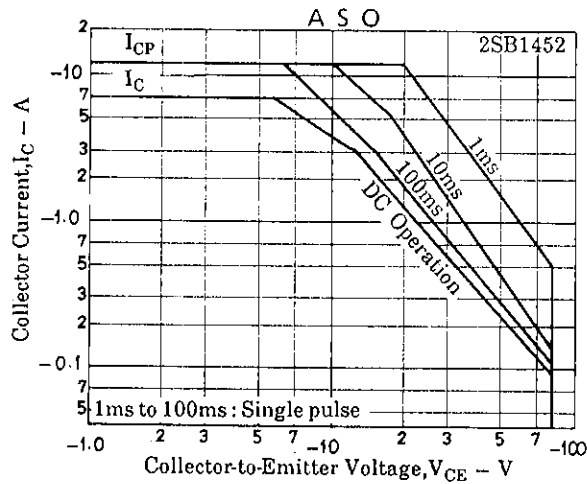
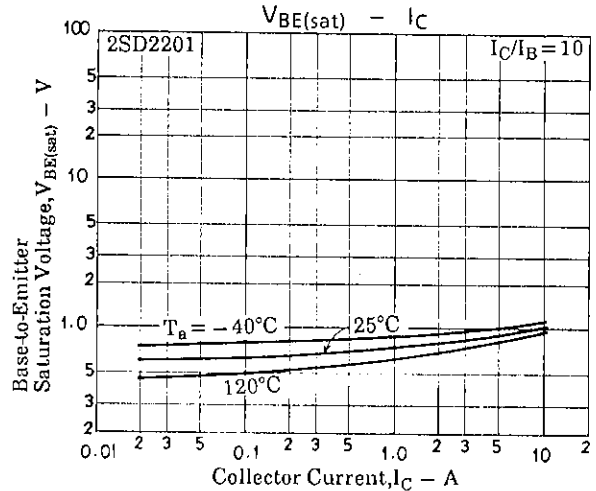
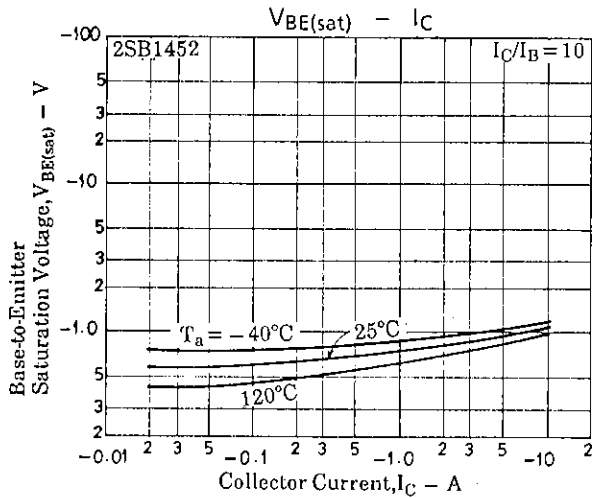
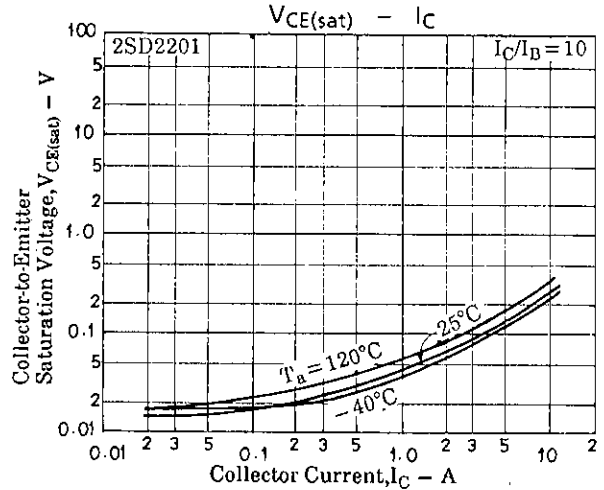
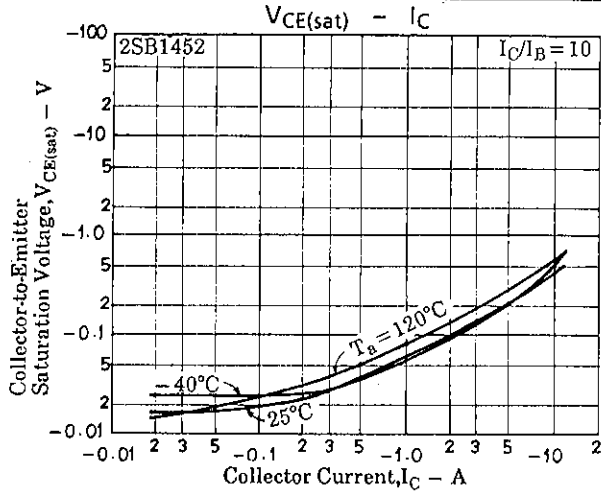
Package Dimensions 2069B
(unit : mm)



2SB1452/2SD2201



2SB1452/2SD2201



- No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.
- Anyone purchasing any products described or contained herein for an above-mentioned use shall:
 - ① Accept full responsibility and indemnify and defend SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use:
 - ② Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.